YAO-3990US3

Appin. No:

10/686,893

eply to Office Action of December 20, 2005

Applicant:

Hidetoshi Ishida, et al.

Filed:

October 16, 2003

Title:

ETCHANT AND METHOD FOR FABRICATING A SEMICONDUCTOR DEVICE

USING THE SAME

TC/A.U.:

2823

Examiner:

Quovaunda Jefferson

Confirmation No.: 8582

Docket No.:

YAO-3990US3

AMENDMENT UNDER 37 C.F.R. § 1.116

Expedited Procedure

Mail Stop AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Responsive to the Office Action dated **December 20, 2005**, please amend the above identified application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 3 of this paper.

TERED BY AIZHO

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